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Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems

Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are Embedded - System On Chip (SoC)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details	
Product Status	Obsolete
Architecture	MCU, FPGA
Core Processor	ARM® Cortex®-M3
Flash Size	128KB
RAM Size	16KB
Peripherals	DMA, POR, WDT
Connectivity	EBI/EMI, I²C, SPI, UART/USART
Speed	80MHz
Primary Attributes	ProASIC®3 FPGA, 60K Gates, 1536D-Flip-Flops
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	288-TFBGA, CSPBGA
Supplier Device Package	288-CSP (11x11)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/a2f060m3e-cs288i

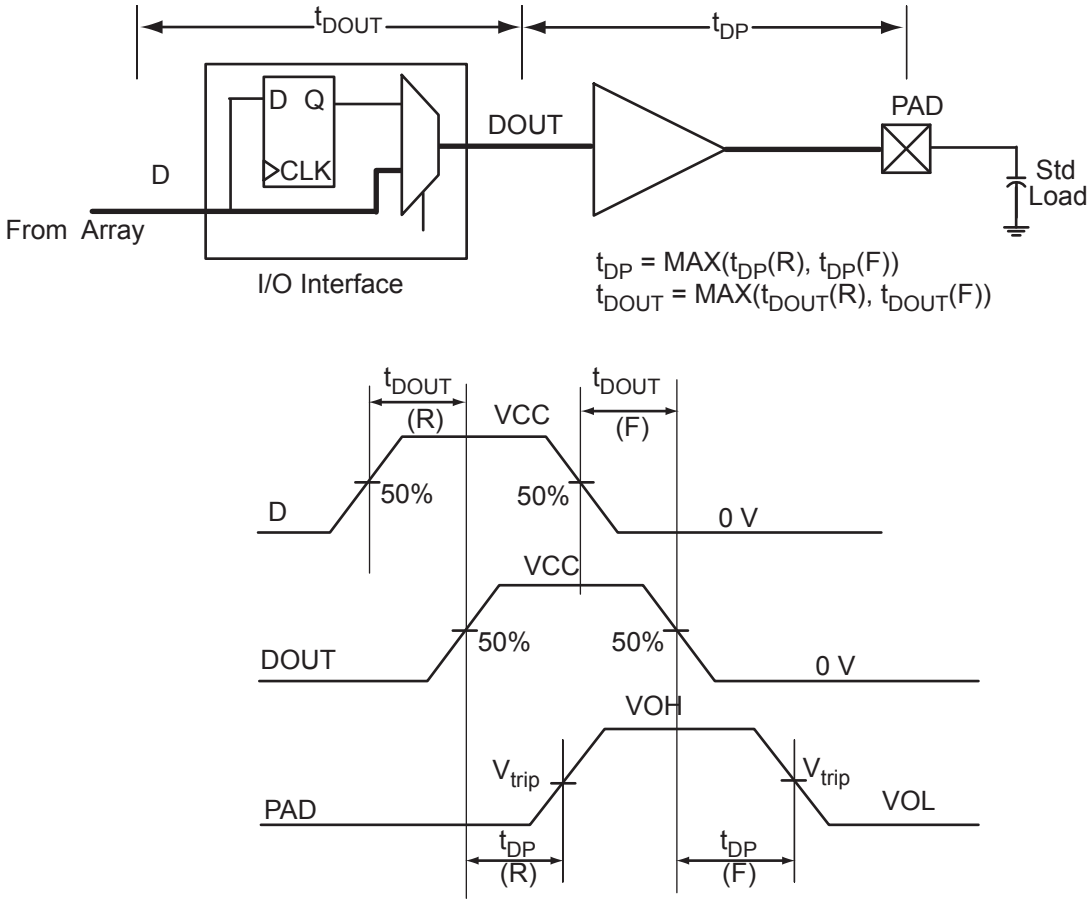

Figure 2-4 • **Output Buffer Model and Delays (example)**

Table 2-28 • I/O Output Buffer Maximum Resistances[1]
Applicable to MSS I/O Banks

Standard	Drive Strength	$R_{PULL\text{-}DOWN}$ (Ω)[2]	$R_{PULL\text{-}UP}$ (Ω)[3]
3.3 V LVTTL / 3.3 V LVCMOS	8mA	50	150
2.5 V LVCMOS	8 mA	50	100
1.8 V LVCMOS	4 mA	100	112
1.5 V LVCMOS	2 mA	200	224

Notes:

1. *These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCCxxxxIOBx, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website.*
2. $R_{(PULL\text{-}DOWN\text{-}MAX)} = (V_{OLspec}) / I_{OLspec}$
3. $R_{(PULL\text{-}UP\text{-}MAX)} = (V_{CCImax} – V_{OHspec}) / I_{OHspec}$

Table 2-29 • I/O Weak Pull-Up/Pull-Down Resistances
Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

VCCxxxxIOBx	$R_{(WEAK\ PULL\text{-}UP)}$[1] ($\Omega$)		$R_{(WEAK\ PULL\text{-}DOWN)}$[2] ($\Omega$)	
	Min.	Max.	Min.	Max.
3.3 V	10 k	45 k	10 k	45 k
2.5 V	11 k	55 k	12 k	74 k
1.8 V	18 k	70 k	17 k	110 k
1.5 V	19 k	90 k	19 k	140 k

Notes:

1. $R_{(WEAK\ PULL\text{-}UP\text{-}MAX)} = (VCCImax – VOHspec) / I_{(WEAK\ PULL\text{-}UP\text{-}MIN)}$
2. $R_{(WEAK\ PULL\text{-}DOWN\text{-}MAX)} = (VOLspec) / I_{(WEAK\ PULL\text{-}DOWN\text{-}MIN)}$

Timing Characteristics

Table 2-56 • 1.5 V LVCMOS High Slew
Worst Commercial-Case Conditions: T_J = 85°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCxxxxIOBx = 1.425 V
Applicable to FPGA I/O Banks, I/O Assigned to EMC I/O Pins

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 m	Std.	0.60	7.79	0.04	1.34	0.39	6.43	7.79	3.19	2.59	8.49	9.85	ns
	–1	0.50	6.49	0.03	1.12	0.32	5.36	6.49	2.66	2.16	7.08	8.21	ns
4 mA	Std.	0.60	4.95	0.04	1.34	0.39	4.61	4.96	3.53	3.19	6.67	7.02	ns
	–1	0.50	4.13	0.03	1.12	0.32	3.85	4.13	2.94	2.66	5.56	5.85	ns
6 mA	Std.	0.60	4.36	0.04	1.34	0.39	4.34	4.36	3.60	3.34	6.40	6.42	ns
	–1	0.50	3.64	0.03	1.12	0.32	3.62	3.64	3.00	2.78	5.33	5.35	ns
8 mA	Std.	0.60	3.89	0.04	1.34	0.39	3.96	3.34	3.72	3.92	6.02	5.40	ns
	–1	0.50	3.24	0.03	1.12	0.32	3.30	2.79	3.10	3.27	5.02	4.50	ns
12 mA	Std.	0.60	3.89	0.04	1.34	0.39	3.96	3.34	3.72	3.92	6.02	5.40	ns
	–1	0.50	3.24	0.03	1.12	0.32	3.30	2.79	3.10	3.27	5.02	4.50	ns

Notes:

1. *Software default selection highlighted in gray.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.*

Table 2-57 • 1.5 V LVCMOS Low Slew
Worst Commercial-Case Conditions: T_J = 85°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCxxxxIOBx = 1.4 V
Applicable to FPGA I/O Banks, I/O Assigned to EMC I/O Pins

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	Std.	0.60	11.96	0.04	1.34	0.39	12.18	11.70	3.20	2.47	14.24	13.76	ns
	–1	0.50	9.96	0.03	1.12	0.32	10.15	9.75	2.67	2.06	11.86	11.46	ns
4 mA	Std.	0.60	9.51	0.04	1.34	0.39	9.68	8.76	3.54	3.07	11.74	10.82	ns
	–1	0.50	7.92	0.03	1.12	0.32	8.07	7.30	2.95	2.56	9.79	9.02	ns
6 mA	Std.	0.60	8.86	0.04	1.34	0.39	9.03	8.17	3.61	3.22	11.08	10.23	ns
	–1	0.50	7.39	0.03	1.12	0.32	7.52	6.81	3.01	2.68	9.24	8.52	ns
8 mA	Std.	0.60	8.44	0.04	1.34	0.39	8.60	8.18	3.73	3.78	10.66	10.24	ns
	–1	0.50	7.04	0.03	1.12	0.32	7.17	6.82	3.11	3.15	8.88	8.53	ns
12 mA	Std.	0.60	8.44	0.04	1.34	0.39	8.60	8.18	3.73	3.78	10.66	10.24	ns
	–1	0.50	7.04	0.03	1.12	0.32	7.17	6.82	3.11	3.15	8.88	8.53	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.

Table 2-58 • 1.5 V LVCMOS High Slew
Worst Commercial-Case Conditions: T_J = 85°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCxxxxIOBx = 3.0 V
Applicable to MSS I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	Units
2 mA	Std.	0.22	3.24	0.09	1.28	1.86	0.22	3.30	3.20	2.24	2.21	ns
	–1	0.18	2.70	0.07	1.07	1.55	0.18	2.75	2.67	1.87	1.85	ns

Notes:

1. *Software default selection highlighted in gray.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.*

Output Enable Register

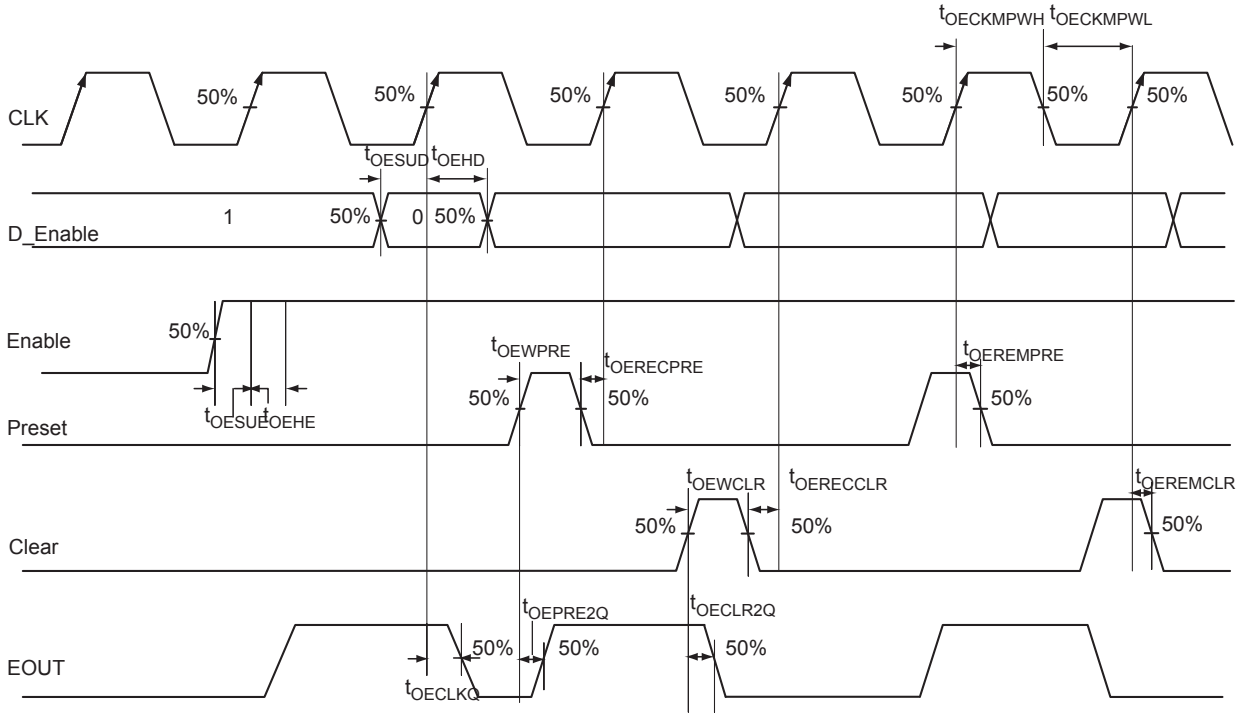

Figure 2-18 • **Output Enable Register Timing Diagram**

Timing Characteristics

Table 2-73 • **Output Enable Register Propagation Delays**
Worst Commercial-Case Conditions: T_J = 85°C, Worst-Case VCC = 1.425 V

Parameter	Description	–1	Std.	Units
t_{OECLKQ}	Clock-to-Q of the Output Enable Register	0.45	0.54	ns
t_{OESUD}	Data Setup Time for the Output Enable Register	0.32	0.38	ns
t_{OEHD}	Data Hold Time for the Output Enable Register	0.00	0.00	ns
t_{OESUE}	Enable Setup Time for the Output Enable Register	0.44	0.53	ns
t_{OEHE}	Enable Hold Time for the Output Enable Register	0.00	0.00	ns
$t_{OECLR2Q}$	Asynchronous Clear-to-Q of the Output Enable Register	0.68	0.81	ns
$t_{OEPRE2Q}$	Asynchronous Preset-to-Q of the Output Enable Register	0.68	0.81	ns
$t_{OEREMCLR}$	Asynchronous Clear Removal Time for the Output Enable Register	0.00	0.00	ns
$t_{ORECCLR}$	Asynchronous Clear Recovery Time for the Output Enable Register	0.23	0.27	ns
$t_{OEREMPRE}$	Asynchronous Preset Removal Time for the Output Enable Register	0.00	0.00	ns
$t_{ORECPRE}$	Asynchronous Preset Recovery Time for the Output Enable Register	0.23	0.27	ns
t_{OEWCLR}	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.22	0.22	ns
t_{OEWPRE}	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.22	0.22	ns
$t_{OECKMPWH}$	Clock Minimum Pulse Width High for the Output Enable Register	0.36	0.36	ns
$t_{OECKMPWL}$	Clock Minimum Pulse Width Low for the Output Enable Register	0.32	0.32	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.

Table 2-92 • JTAG 1532
Worst Commercial-Case Conditions: T_J = 85°C, Worst-Case VCC = 1.425 V

Parameter	Description	–1	Std.	Units
t_{RSTB2Q}	Reset to Q (data out)	26.67	30.67	ns
F_{TCKMAX}	TCK Maximum Frequency	19.00	21.85	MHz
$t_{TRSTREM}$	ResetB Removal Time	0.00	0.00	ns
$t_{TRSTREC}$	ResetB Recovery Time	0.27	0.31	ns
$t_{TRSTMPW}$	ResetB Minimum Pulse	TBD	TBD	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-9 for derating values.

Compile and Debug

Microsemi's SoftConsole is a free Eclipse-based IDE that enables the rapid production of C and C++ executables for Microsemi FPGA and cSoCs using Cortex-M3, Cortex-M1 and Core8051s. For SmartFusion support, SoftConsole includes the GNU C/C++ compiler and GDB debugger. Additional examples can be found on the SoftConsole page:

- Using UART with SmartFusion: SoftConsole Standalone Flow Tutorial
  - Design Files
- Displaying POT Level with LEDs: Libero SoC and SoftConsole Flow Tutorial for SmartFusion
  - Design Files

IAR Embedded Workbench® for ARM/Cortex is an integrated development environment for building and debugging embedded ARM applications using assembler, C and C++. It includes a project manager, editor, build and debugger tools with support for RTOS-aware debugging on hardware or in a simulator.

- Designing SmartFusion cSoC with IAR Systems
- IAR Embedded Workbench IDE User Guide for ARM
- Download Evaluation or Kickstart version of IAR Embedded Workbench for ARM

Keil's Microcontroller Development Kit comes in two editions: MDK-ARM and MDK Basic. Both editions feature µVision®, the ARM Compiler, MicroLib, and RTX, but the MDK Basic edition is limited to 256K so that small applications are more affordable.

- Designing SmartFusion cSoC with Keil
- Using Keil µVision and Microsemi SmartFusion cSoC
  - Programming file for use with this tutorial
- Keil Microcontroller Development Kit for ARM Product Manuals
- Download Evaluation version of Keil MDK-ARM

CMSIS COMPLIANT ARM® Cortex™ Microcontroller Software Interface Standard	Microsemi	KEIL™ An ARM® Company	IAR SYSTEMS
Software IDE	**SoftConsole**	**Vision IDE**	**Embedded Workbench**
Website	www.microsemi.com/soc	www.keil.com	www.iar.com
Free versions from SoC Products Group	Free with Libero SoC	32 K code limited	32 K code limited
Available from Vendor	N/A	Full version	Full version
Compiler	GNU GCC	RealView C/C++	IAR ARM Compiler
Debugger	GDB debug	Vision Debugger	C-SPY Debugger
Instruction Set Simulator	No	Vision Simulator	Yes
Debug Hardware	FlashPro4	ULINK2 or ULINK-ME	J-LINK or J-LINK Lite

Operating Systems

FreeRTOS™ is a portable, open source, royalty free, mini real-time kernel (a free-to-download and free-to-deploy RTOS that can be used in commercial applications without any requirement to expose your proprietary source code). FreeRTOS is scalable and designed specifically for small embedded systems. This FreeRTOS version ported by Microsemi is 6.0.1. For more information, visit the FreeRTOS website: www.freertos.org

- SmartFusion Webserver Demo Using uIP and FreeRTOS
- SmartFusion cSoC: Running Webserver, TFTP on lwIP TCP/IP Stack Application Note

- Flash File System (RL-Flash) allows your embedded applications to create, save, read, and modify files in standard storage devices such as ROM, RAM, or FlashROM, using a standard serial peripheral interface (SPI). Many ARM-based microcontrollers have a practical requirement for a standard file system. With RL-FlashFS you can implement new features in embedded applications such as data logging, storing program state during standby modes, or storing firmware upgrades.

Micrium, in addition to µC/OS-III®, offers the following support for SmartFusion cSoC:

- µC/TCP-IP™ is a compact, reliable, and high-performance stack built from the ground up by Micrium and has the quality, scalability, and reliability that translates into a rapid configuration of network options, remarkable ease-of-use, and rapid time-to-market.
- µC/Probe™ is one of the most useful tools in embedded systems design and puts you in the driver's seat, allowing you to take charge of virtually any variable, memory location, and I/O port in your embedded product, while your system is running.

References

PCB Files

A2F500 SmartFusion Development Kit PCB Files

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=130770

A2F200 SmartFusion Development Kit PCB Files

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=130773

Application Notes

SmartFusion cSoC Board Design Guidelines

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=129815

Re-Programming the eNVM Blocks Using the Cortex-M3

In this mode the Cortex-M3 is executing the eNVM programming algorithm from eSRAM. Since individual pages (132 bytes) of the eNVM can be write-protected, the programming algorithm software can be protected from inadvertent erasure. When reprogramming the eNVM, both MSS I/Os and FPGA I/Os are available as interfaces for sourcing the new eNVM image. The SoC Products Group provides working example projects for SoftConsole, IAR, and Keil development environments. These can be downloaded via the SoC Products Group Firmware Catalog.

Alternately, the eNVM can be reprogrammed by the Cortex-M3 via the IAP driver. This is necessary when using an encrypted image.

Secure Programming

For background, refer to the "Security in Low Power Flash Devices" chapter of the *Fusion FPGA Fabric User's Guide* on the SoC Products Group website. SmartFusion ISP behaves identically to Fusion ISP. IAP of SmartFusion cSoCs is accomplished by using the IAP driver. Only the FPGA fabric and the eNVM can be reprogrammed with the protection of security measures by using the IAP driver.

Typical Programming and Erase Times

Table 4-3 documents the typical programming and erase times for two components of SmartFusion cSoCs, FPGA fabric and eNVM, using the SoC Products Group's FlashPro hardware and software. These times will be different for other ISP and IAP methods. The **Program** action in FlashPro software includes erase, program, and verify to complete.

The typical programming (including erase) time per page of the eNVM is 8 ms.

***Table 4-3* • Typical Programming and Erase Times**

	FPGA Fabric (seconds)			eNVM (seconds)			FlashROM (seconds)		
	A2F060	**A2F200**	**A2F500**	**A2F060**	**A2F200**	**A2F500**	**A2F060**	**A2F200**	**A2F500**
Erase	21	21	21	N/A	N/A	N/A	21	21	21
Program	28	35	48	18	39	71	22	22	22
Verify	2	6	12	9	18	37	1	1	1

References

User's Guides

DirectC User's Guide

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=132588

In-System Programming (ISP) of Microsemi's Low-Power Flash Devices Using FlashPro4/3/3X

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=129973

Programming Flash Devices HandBook

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=129930

Application Notes on IAP Programming Technique

SmartFusion cSoC: Programming FPGA Fabric and eNVM Using In-Application Programming Interface App Note

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=129818

SmartFusion cSoC: Basic Bootloader and Field Upgrade eNVM Through IAP Interface App Note

http://www.microsemi.com/index.php?option=com_docman&task=doc_download&gid=129823

Name	Type	Description
VCCFPGAIOB5	Supply	Digital supply to the FPGA fabric I/O bank 5 (west FPGA I/O bank) for the output buffers and I/O logic. Each bank can have a separate VCCFPGAIO connection. All I/Os in a bank will run off the same VCCFPGAIO supply. VCCFPGAIO can be 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. Unused I/O banks should have their corresponding VCCFPGAIO pins tied to GND.
VCCLPXTAL	Supply	Analog supply to the low power 32 KHz crystal oscillator. Always power this pin.[1]
VCCMAINXTAL	Supply	Analog supply to the main crystal oscillator circuit. Always power this pin.[1]
VCCMSSIOB2	Supply	Supply voltage to the microcontroller subsystem I/O bank 2 (east MSS I/O bank) for the output buffers and I/O logic. Each bank can have a separate VCCMSSIO connection. All I/Os in a bank will run off the same VCCMSSIO supply. VCCMSSIO can be 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. Unused I/O banks should have their corresponding VCCMSSIO pins tied to GND.
VCCMSSIOB4	Supply	Supply voltage to the microcontroller subsystem I/O bank 4 (west MSS I/O bank) for the output buffers and I/O logic. Each bank can have a separate VCCMSSIO connection. All I/Os in a bank will run off the same VCCMSSIO supply. VCCMSSIO can be 1.5 V, 1.8 V, 2.5 V, or 3.3 V, nominal voltage. Unused I/O banks should have their corresponding VCCMSSIO pins tied to GND.
VCCPLLx	Supply	Analog 1.5 V supply to the PLL. Always power this pin.
VCCRCOSC	Supply	Analog supply to the integrated RC oscillator circuit. Always power this pin.[1]
VCOMPLAx	Supply	Analog ground for the PLL
VDDBAT	Supply	External battery connection to the low power 32 KHz crystal oscillator (along with VCCLPXTAL), RTC, and battery switchover circuit. Can be pulled down if unused.

Notes:

1. *The following 3.3 V supplies should be connected together while following proper noise filtering practices: VCC33A, VCC33ADCx, VCC33AP, VCC33SDDx, VCCMAINXTAL, and VCCLPXTAL.*
2. *The following 1.5 V supplies should be connected together while following proper noise filtering practices: VCC, VCC15A, and VCC15ADCx.*
3. *For more details on VCCPLLx capacitor recommendations, refer to the application note AC359, SmartFusion cSoC Board Design Guidelines, the "PLL Power Supply Decoupling Scheme" section.*

Special Function Pins

Name	Type	Polarity/Bus Size	Description
NC			No connect This pin is not connected to circuitry within the device. These pins can be driven to any voltage or can be left floating with no effect on the operation of the device.
DC			Do not connect. This pin should not be connected to any signals on the PCB. These pins should be left unconnected.
LPXIN	In	1	Low power 32 KHz crystal oscillator. Input from the 32 KHz oscillator. Pin for connecting a low power 32 KHz watch crystal. If not used, the LPXIN pin can be left floating. For more information, see the PLLs, Clock Conditioning Circuitry, and On-Chip Crystal Oscillators section in the *SmartFusion Microcontroller Subsystem User's Guide*.
LPXOUT	In	1	Low power 32 KHz crystal oscillator. Output to the 32 KHz oscillator. Pin for connecting a low power 32 KHz watch crystal. If not used, the LPXOUT pin can be left floating. For more information, see the PLLs, Clock Conditioning Circuitry, and On-Chip Crystal Oscillators section in the *SmartFusion Microcontroller Subsystem User's Guide*.
MAINXIN	In	1	Main crystal oscillator circuit. Input to the crystal oscillator circuit. Pin for connecting an external crystal, ceramic resonator, or RC network. When using an external crystal or ceramic oscillator, external capacitors are also recommended. Refer to documentation from the crystal oscillator manufacturer for proper capacitor value. If an external RC network or clock input is used, the RC components are connected to the MAINXIN pin, with MAINXOUT left floating. When the main crystal oscillator is not being used, MAINXIN and MAINXOUT pins can be left floating. For more information, see the PLLs, Clock Conditioning Circuitry, and On-Chip Crystal Oscillators section in the *SmartFusion Microcontroller Subsystem User's Guide*.
MAINXOUT	Out	1	Main crystal oscillator circuit. Output from the crystal oscillator circuit. Pin for connecting external crystal or ceramic resonator. When using an external crystal or ceramic oscillator, external capacitors are also recommended. Refer to documentation from the crystal oscillator manufacturer for proper capacitor value. If an external RC network or clock input is used, the RC components are connected to the MAINXIN pin, with MAINXOUT left floating. When the main crystal oscillator is not being used, MAINXIN and MAINXOUT pins can be left floating. For more information, see the PLLs, Clock Conditioning Circuitry, and On-Chip Crystal Oscillators section in the *SmartFusion Microcontroller Subsystem User's Guide*.

***Table 5-1* • Recommended Tie-Off Values for the TCK and TRST Pins**

VJTAG	Tie-Off Resistance[1, 2]
VJTAG at 3.3 V	200 Ω to 1 kΩ
VJTAG at 2.5 V	200 Ω to 1 kΩ
VJTAG at 1.8 V	500 Ω to 1 kΩ
VJTAG at 1.5 V	500 Ω to 1 kΩ

Notes:

1. *The TCK pin can be pulled up/down.*
2. *The TRST pin can only be pulled down.*

1. *Equivalent parallel resistance if more than one device is on JTAG chain.*

Pin No.	CS288		
	A2F060 Function	A2F200 Function	A2F500 Function
C21	IO17NDB0V0	GBA2/IO20PDB1V0	GBA2/IO27PDB1V0
D1	EMC_DB[14]/IO45NDB5V0	EMC_DB[14]/GAB2/IO71NDB5V0	EMC_DB[14]/GAB2/IO88NDB5V0
D3	VCCFPGAIOB5	VCCFPGAIOB5	VCCFPGAIOB5
D19	GND	GND	GND
D21	VCCFPGAIOB1	VCCFPGAIOB1	VCCFPGAIOB1
E1	EMC_DB[13]/IO44PDB5V0	EMC_DB[13]/GAC2/IO70PDB5V0	EMC_DB[13]/GAC2/IO87PDB5V0
E3	EMC_DB[12]/IO44NDB5V0	EMC_DB[12]/IO70NDB5V0	EMC_DB[12]/IO87NDB5V0
E5	GNDQ	GNDQ	GNDQ
E6	EMC_BYTEN[0]/IO02NDB0V0	EMC_BYTEN[0]/GAC0/IO02NDB0V0	EMC_BYTEN[0]/GAC0/IO07NDB0V0
E7	EMC_BYTEN[1]/IO02PDB0V0	EMC_BYTEN[1]/GAC1/IO02PDB0V0	EMC_BYTEN[1]/GAC1/IO07PDB0V0
E8	EMC_OEN1_N/IO03PDB0V0	EMC_OEN1_N/IO03PDB0V0	EMC_OEN1_N/IO08PDB0V0
E9	EMC_AB[3]/IO05PDB0V0	EMC_AB[3]/IO05PDB0V0	EMC_AB[3]/IO09PDB0V0
E10	EMC_AB[10]/IO09NDB0V0	EMC_AB[10]/IO09NDB0V0	EMC_AB[10]/IO11NDB0V0
E11	EMC_AB[7]/IO07PDB0V0	EMC_AB[7]/IO07PDB0V0	EMC_AB[7]/IO12PDB0V0
E12	EMC_AB[13]/IO10PDB0V0	EMC_AB[13]/IO10PDB0V0	EMC_AB[13]/IO14PDB0V0
E13	EMC_AB[16]/IO12NDB0V0	EMC_AB[16]/IO12NDB0V0	EMC_AB[16]/IO17NDB0V0
E14	EMC_AB[17]/IO12PDB0V0	EMC_AB[17]/IO12PDB0V0	EMC_AB[17]/IO17PDB0V0
E15	GCC0/IO18NPB0V0	GCB0/IO27NDB1V0	GCB0/IO34NDB1V0
E16	GCA1/IO20PPB0V0	GCB1/IO27PDB1V0	GCB1/IO34PDB1V0
E17	GCC1/IO18PPB0V0	GCB2/IO24PDB1V0	GCB2/IO33PDB1V0
E19	GCB2/IO22PPB1V0	GCA0/IO28NDB1V0	GCA0/IO36NDB1V0 *
E21	IO21NDB1V0	GCA1/IO28PDB1V0	GCA1/IO36PDB1V0 *
F1	VCCFPGAIOB5	VCCFPGAIOB5	VCCFPGAIOB5
F3	GFB2/IO42NDB5V0	GFB2/IO68NDB5V0	GFB2/IO85NDB5V0
F5	GFA2/IO42PDB5V0	GFA2/IO68PDB5V0	GFA2/IO85PDB5V0
F6	EMC_DB[11]/IO43PDB5V0	EMC_DB[11]/IO69PDB5V0	EMC_DB[11]/IO86PDB5V0
F7	GND	GND	GND
F8	NC	GFC1/IO66PPB5V0	GFC1/IO83PPB5V0
F9	VCCFPGAIOB0	VCCFPGAIOB0	VCCFPGAIOB0
F10	EMC_AB[11]/IO09PDB0V0	EMC_AB[11]/IO09PDB0V0	EMC_AB[11]/IO11PDB0V0
F11	EMC_AB[6]/IO07NDB0V0	EMC_AB[6]/IO07NDB0V0	EMC_AB[6]/IO12NDB0V0

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin Number	PQ208	
	A2F200	A2F500
32	VCCRCOSC	VCCRCOSC
33	MSS_RESET_N	MSS_RESET_N
34	VCCESRAM	VCCESRAM
35	MAC_MDC/IO48RSB4V0	MAC_MDC/IO57RSB4V0
36	MAC_MDIO/IO49RSB4V0	MAC_MDIO/IO58RSB4V0
37	MAC_TXEN/IO52RSB4V0	MAC_TXEN/IO61RSB4V0
38	MAC_CRSDV/IO51RSB4V0	MAC_CRSDV/IO60RSB4V0
39	MAC_RXER/IO50RSB4V0	MAC_RXER/IO59RSB4V0
40	GND	GND
41	VCCMSSIOB4	VCCMSSIOB4
42	VCC	VCC
43	MAC_TXD[0]/IO56RSB4V0	MAC_TXD[0]/IO65RSB4V0
44	MAC_TXD[1]/IO55RSB4V0	MAC_TXD[1]/IO64RSB4V0
45	MAC_RXD[0]/IO54RSB4V0	MAC_RXD[0]/IO63RSB4V0
46	MAC_RXD[1]/IO53RSB4V0	MAC_RXD[1]/IO62RSB4V0
47	MAC_CLK	MAC_CLK
48	GNDSDD0	GNDSDD0
49	VCC33SDD0	VCC33SDD0
50	VCC15A	VCC15A
51	PCAP	PCAP
52	NCAP	NCAP
53	VCC33AP	VCC33AP
54	VCC33N	VCC33N
55	SDD0	SDD0
56	GNDA	GNDA
57	GNDAQ	GNDAQ
58	ABPS0	ABPS0
59	ABPS1	ABPS1
60	CM0	CM0
61	TM0	TM0
62	GNDTM0	GNDTM0

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin Number	PQ208	
	A2F200	A2F500
125	TMS	TMS
126	TDO	TDO
127	TRSTB	TRSTB
128	VJTAG	VJTAG
129	VDDBAT	VDDBAT
130	VCCLPXTAL	VCCLPXTAL
131	LPXOUT	LPXOUT
132	LPXIN	LPXIN
133	GNDLPXTAL	GNDLPXTAL
134	GNDMAINXTAL	GNDMAINXTAL
135	MAINXOUT	MAINXOUT
136	MAINXIN	MAINXIN
137	VCCMAINXTAL	VCCMAINXTAL
138	GND	GND
139	VCC	VCC
140	VPP	VPP
141	VCCFPGAIOB1	VCCFPGAIOB1
142	GDA0/IO31NDB1V0	GDA0/IO40NDB1V0
143	GDA1/IO31PDB1V0	GDA1/IO40PDB1V0
144	GDC0/IO29NSB1V0	GDC0/IO38NSB1V0
145	GCA0/IO28NDB1V0	GCA0/IO36NDB1V0 *
146	GCA1/IO28PDB1V0	GCA1/IO36PDB1V0 *
147	VCCFPGAIOB1	VCCFPGAIOB1
148	GND	GND
149	VCC	VCC
150	IO25NDB1V0	IO30NDB1V0
151	GCC2/IO25PDB1V0	GBC2/IO30PDB1V0
152	IO23NDB1V0	IO28NDB1V0
153	GCA2/IO23PDB1V0	GCA2/IO28PDB1V0 *
154	GBC2/IO21PSB1V0	GBB2/IO27NDB1V0
155	GBA2/IO20PSB1V0	GBA2/IO27PDB1V0

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin Number	FG484	
	A2F200 Function	A2F500 Function
H7	GND	GND
H8	VCC	VCC
H9	GND	GND
H10	VCC	VCC
H11	GND	GND
H12	VCC	VCC
H13	GND	GND
H14	VCC	VCC
H15	GND	GND
H16	VCCFPGAIOB1	VCCFPGAIOB1
H17	IO25NDB1V0	IO29NDB1V0
H18	GCC2/IO25PDB1V0	GCC2/IO29PDB1V0
H19	GND	GND
H20	GCC0/IO26NPB1V0	GCC0/IO35NPB1V0
H21	VCCFPGAIOB1	VCCFPGAIOB1
H22	GCB0/IO27NDB1V0	GCB0/IO34NDB1V0
J1	EMC_DB[6]/GEB0/IO62NDB5V0	EMC_DB[6]/GEB0/IO79NDB5V0
J2	EMC_DB[5]/GEA1/IO61PDB5V0	EMC_DB[5]/GEA1/IO78PDB5V0
J3	EMC_DB[4]/GEA0/IO61NDB5V0	EMC_DB[4]/GEA0/IO78NDB5V0
J4	EMC_DB[3]/GEC2/IO60PPB5V0	EMC_DB[3]/GEC2/IO77PPB5V0
J5	VCCFPGAIOB5	VCCFPGAIOB5
J6	GFA0/IO64NDB5V0	GFA0/IO81NDB5V0
J7	VCCFPGAIOB5	VCCFPGAIOB5
J8	GND	GND
J9	VCC	VCC
J10	GND	GND
J11	VCC	VCC
J12	GND	GND
J13	VCC	VCC
J14	GND	GND
J15	VCC	VCC
J16	GND	GND
J17	NC	IO37PDB1V0
J18	VCCFPGAIOB1	VCCFPGAIOB1

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Pin Number	FG484	
	A2F200 Function	A2F500 Function
T1	GND	GND
T2	VCCMSSIOB4	VCCMSSIOB4
T3	GPIO_8/IO39RSB4V0	GPIO_8/IO48RSB4V0
T4	GPIO_11/IO57RSB4V0	GPIO_11/IO66RSB4V0
T5	GND	GND
T6	MAC_CLK	MAC_CLK
T7	VCCMSSIOB4	VCCMSSIOB4
T8	VCC33SDD0	VCC33SDD0
T9	VCC15A	VCC15A
T10	GNDAQ	GNDAQ
T11	GND33ADC0	GND33ADC0
T12	ADC7	ADC7
T13	NC	TM4
T14	NC	VAREF2
T15	VAREFOUT	VAREFOUT
T16	VCCMSSIOB2	VCCMSSIOB2
T17	SPI_1_DO/GPIO_24	SPI_1_DO/GPIO_24
T18	GND	GND
T19	NC	NC
T20	NC	NC
T21	VCCMSSIOB2	VCCMSSIOB2
T22	GND	GND
U1	GND	GND
U2	GPIO_5/IO42RSB4V0	GPIO_5/IO51RSB4V0
U3	GPIO_10/IO58RSB4V0	GPIO_10/IO67RSB4V0
U4	VCCMSSIOB4	VCCMSSIOB4
U5	MAC_RXD[1]/IO53RSB4V0	MAC_RXD[1]/IO62RSB4V0
U6	NC	NC
U7	VCC33AP	VCC33AP
U8	VCC33N	VCC33N
U9	CM1	CM1
U10	VAREF0	VAREF0
U11	GND33ADC1	GND33ADC1
U12	ADC4	ADC4

Notes:

1. *Shading denotes pins that do not have completely identical functions from density to density. For example, the bank assignment can be different for an I/O, or the function might be available only on a larger density device.*
2. **: Indicates that the signal assigned to the pins as a CLKBUF/CLKBUF_LVPECL/CLKBUF_LVDS goes through a glitchless mux. In order for the glitchless mux to operate correctly, the signal must be a free-running clock signal. Refer to the 'Glitchless MUX' section in the SmartFusion Microcontroller Subsystem User's Guide for more details.*

Revision	Changes	Page
Revision 7 (continued)	Usage instructions, such as how to handle the pin when unused, were added for the following supply pins (SAR 29769): "VCC15A" "VCC15ADC0" through "VCC15ADC2" "VCC33ADC0" through "VCC33ADC2" "VCC33AP" "VCC33ADC2" "VCCLPXTAL" "VCCMAINXTAL" "VCCMSSIOB2" "VCCPLLx" "VCCRCOSC" "VDDBAT"	5-2 through 5-3
	The "IO" description was revised to clarify the definitions of u, I/O pair, and w, differential pair (SAR 31147). Information on configuration of unused I/Os (including unused MSS I/Os, SAR 26891) was added (SAR 32643).	5-6
	Usage instructions were added for the following pins (SAR 29769): "MSS_RESET_N" "TCK" "TMS" "TRSTB" "MAC_CLK"	5-9 through 5-13
	Package names used in the "Pin Assignment Tables" section were revised to match standards given in *Package Mechanical Drawings* (SAR 27395).	5-18
	The pin assignments for A2F060 for "TQ144" and "FG256" have been revised due to the device status change from advance to preliminary (SAR 33068). The "TQ144" and "FG256" pin assignment sections previously compared functions between A2F060/A2F200 devices in one table and A2F200/A2F500 in a separate table. Functions for all three devices have now been combined into one table for each package (SAR 33072).	5-18, 5-42
	The "PQ208" pin table was revised for A2F500 to remove EMC functions, which are not available for this device/package combination (SAR 33041).	5-34
Revision 6 (March 2011)	The "PQ208" package was added to product tables and "Product Ordering Codes" for A2F200 and A2F500 (SAR 31005).	III
	The "Package I/Os: MSS + FPGA I/Os" table was revised to add the CS288 package for A2F060 and the PQ208 package for A2F200 and A2F500. A row was added for shared analog inputs (SAR 31034).	III
	The "SmartFusion cSoC Device Status" table was updated (SAR 31084).	III
	VCCESRAM was added to Table 2-1 • Absolute Maximum Ratings, Table 2-3 • Recommended Operating Conditions[5,6], Table 2-8 • Power Supplies Configuration, and the "Supply Pins" table (SAR 31035).	2-1, 2-3, 2-10, 5-1
	The following note was removed from Table 2-8 • Power Supplies Configuration (SAR 30984): "Current monitors and temperature monitors should not be used when Power-Down and/or Sleep mode are required by the application."	2-10

Revision	Changes	Page
Revision 6 (continued)	Dynamic power values were updated in the following tables. The table subtitles changed where FPGA I/O banks were involved to note "I/O assigned to EMC I/O pins" (SAR 30987). Table 2-10 • Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings Table 2-13 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings.	2-10 2-11
	The "Timing Model" was updated (SAR 30986).	2-19
	Values in the timing tables for the following sections were updated. Table subtitles were updated for FPGA I/O banks to note "I/O assigned to EMC I/O pins" (SAR 30986). "Overview of I/O Performance" section: Table 2-24, Table 2-25 "Detailed I/O DC Characteristics" section: Table 2-38, Table 2-39, Table 2-40, Table 2-44, Table 2-45, Table 2-46, Table 2-50, Table 2-51, Table 2-52, Table 2-56, Table 2-57, Table 2-58, Table 2-61, Table 2-62 "LVDS" section: Table 2-65 "LVPECL" section: Table 2-68 "Global Tree Timing Characteristics" section: Table 2-80, Table 2-81	2-23 2-26 2-40 2-42 2-59
	The "PQ208" section and pin tables are new (SAR 31005).	5-34
	Global clocks were removed from the A2F060 pin table for the "CS288" and "FG256" packages, resulting in changed function names for affected pins (SAR 31033).	5-43
Revision 5 (December 2010)	Table 2-2 • Analog Maximum Ratings was revised. The recommended CM[n] pad voltage (relative to ground) was changed from –11 to –0.3 (SAR 28219).	2-2
	Table 2-7 • Temperature and Voltage Derating Factors for Timing Delays was revised to change the values for 100ºC.	2-9
	Power-down and Sleep modes, and all associated notes, were removed from Table 2-8 • Power Supplies Configuration (SAR 29479). IDC3 and IDC4 were renamed to IDC1 and IDC2 (SAR 29478). These modes are no longer supported. A note was added to the table stating that current monitors and temperature monitors should not be used when Power-down and/or Sleep mode are required by the application.	2-10
	The "Power-Down and Sleep Mode Implementation" section was deleted (SAR 29479).	N/A
	Values for PAC9 and PAC10 for LVDS and LVPECL were revised in Table 2-10 • Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings and Table 2-12 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings*.	2-10, 2-11
	Values for PAC1 through PAC4, PDC1, and PDC2 were added for A2F500 in Table 2-14 • Different Components Contributing to Dynamic Power Consumption in SmartFusion cSoCs and Table 2-15 • Different Components Contributing to the Static Power Consumption in SmartFusion cSoCs	2-12, 2-13
	The equation for "Total Dynamic Power Consumption—P_{DYN}" in "SoC Mode" was revised to add P_{MSS}. The "Microcontroller Subsystem Dynamic Contribution—P_{MSS}" section is new (SAR 29462).	2-14, 2-18
	Information in Table 2-24 • Summary of I/O Timing Characteristics—Software Default Settings (applicable to FPGA I/O banks) and Table 2-25 • Summary of I/O Timing Characteristics—Software Default Settings (applicable to MSS I/O banks) was updated.	2-25

Revision	Changes	Page
Revision 3 (continued)	In Table 2-3 • Recommended Operating Conditions[5,6], the VDDBAT recommended operating range was changed from "2.97 to 3.63" to "2.7 to 3.63" (SAR 25246). Recommended operating range was changed to "3.15 to 3.45" for the following voltages: VCC33A VCC33ADCx VCC33AP VCC33SDDx VCCMAINXTAL VCCLPXTAL Two notes were added to the table (SAR 27109): 1. *The following 3.3 V supplies should be connected together while following proper noise filtering practices: VCC33A, VCC33ADCx, VCC33AP, VCC33SDDx, VCCMAINXTAL, and VCCLPXTAL.* 2. *The following 1.5 V supplies should be connected together while following proper noise filtering practices: VCC, VCC15A, and VCC15ADCx.*	2-3
	In Table 2-3 • Recommended Operating Conditions[5,6], the description for VCCLPXTAL was corrected to change "32 Hz" to "32 KHz" (SAR 27110).	2-3
	The "Power Supply Sequencing Requirement" section is new (SAR 27178).	2-4
	Table 2-8 • Power Supplies Configuration was revised to change most on/off entries to voltages. Note 5 was added, stating that "on" means proper voltage is applied. The values of 6 µA and 16 µA were removed for IDC1 and IDC2 for 3.3 V. A note was added for IDC1 and IDC2: "Power mode and Sleep mode are consuming higher current than expected in the current version of silicon. These specifications will be updated when new version of the silicon is available" (SAR 27926).	2-10
	The "Power-Down and Sleep Mode Implementation" section is new (SAR 27178).	2-11
	A note was added to Table 2-86 • SmartFusion CCC/PLL Specification, pertaining to f_{out_CCC}, stating that "one of the CCC outputs (GLA0) is used as an MSS clock and is limited to 100 MHz (maximum) by software" (SAR 26388).	2-63
	Table 2-90 • eNVM Block Timing, Worst Commercial Case Conditions: T_J = 85°C, VCC = 1.425 V was revised. Values were included for A2F200 and A2F500, for –1 and Std. speed grades. A note was added to define 6:1:1:1 and 5:1:1:1 (SAR 26166).	2-76
	The units were corrected (mV instead of V) for input referred offset voltage, GDEC[1:0] = 00 in Table 2-96 • ABPS Performance Specifications (SAR 25381).	2-82
	The test condition values for operating current (ICC33A, typical) were changed in Table 2-99 • Voltage Regulator (SAR 26465).	2-87
	Figure 2-45 • Typical Output Voltage was revised to add legends for the three curves, stating the load represented by each (SAR 25247).	2-88
	The "SmartFusion Programming" chapter was moved to this document from the SmartFusion Subsystem Microcontroller User's Guide (SAR 26542). The "Typical Programming and Erase Times" section was added to this chapter.	4-7
	Figure 4-1 • TRSTB Logic was revised to change 1.5 V to "VJTAG (1.5 V to 3.3 V nominal)" (SAR 24694).	4-8